NSN 5961-01-214-7044

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Inclosure Material:

Plastic

Overall Length:

11.5 millimeters

Overall Height:

3.1 millimeters

Overall Width:

8.5 millimeters

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-126

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-180.0 collector to base voltage/static/emitter open and -160.0 collector to emitter voltage/static/base open and -5.0 emitter to base

voltage, static, collector open

Current Rating Per Characteristic:

-50.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector

Transfer Ratio:

60.0 static forward current transfer ratio, common-emitter and 320.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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